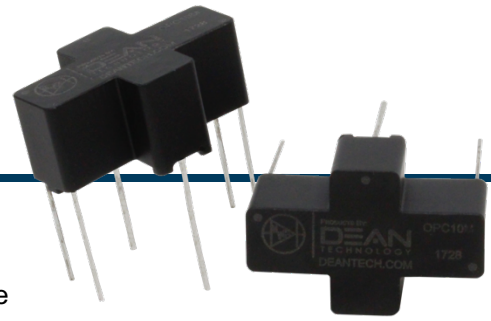




OPC10M

10kV, 80mA
Optical Switch



Features

- High Voltage Optocoupler
- Integrated Low Voltage LED Drivers with 10kV Photo Detector Diode
- Black Casing, Light Tight Packaging
- Custom Versions Available

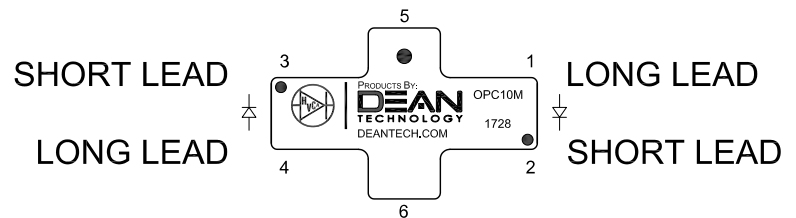
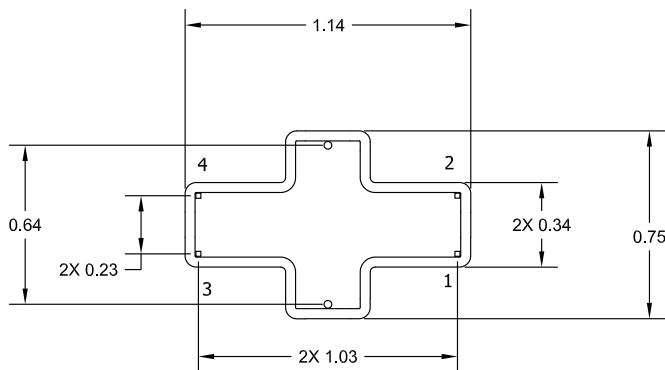
Specifications¹

| Part Number | V _{RRM} V | I _{FAVM} mA | V _F V | I _R μA | I _{FSM} A | C _J pF | CTR % | t _{ON} μs | t _{OFF} μs | Insulation Voltage V | I _{LED} mA | V _{FLED} V | V _{RLED} V |
|-------------|--------------------|----------------------|------------------|-------------------|--------------------|-------------------|-------|--------------------|---------------------|----------------------|---------------------|---------------------|---------------------|
| OPC10M | 10000 | 80 | 12 | 25 | 10 | 3 | 0.48 | 2 | 2 | 12000 | 100 | 1.25 | 5 |

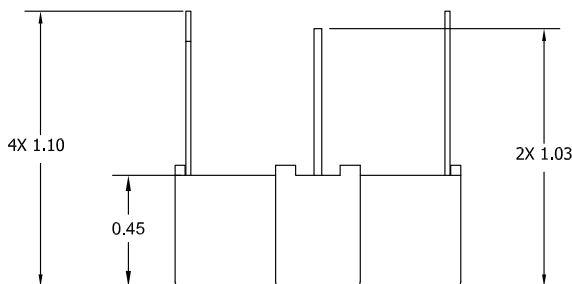
| Temperature °C | |
|------------------------------|------------|
| Operating Temperature | -40 to 85 |
| Storage Temperature | -55 to 100 |
| Maximum Junction Temperature | 100 |

¹25°C ambient temperature unless stated otherwise.

Drawings



Dimensions in inches, tolerances ±0.020 except as noted



| Pin Dimensions | |
|----------------|---|
| 1, 2, 3, 4 | Round Pins 0.020" [0.51 mm] to 0.023" [0.58 mm] |
| 5, 6 | Round Pins 0.029" [0.74 mm] to 0.030" [0.76 mm] |



Test Circuit

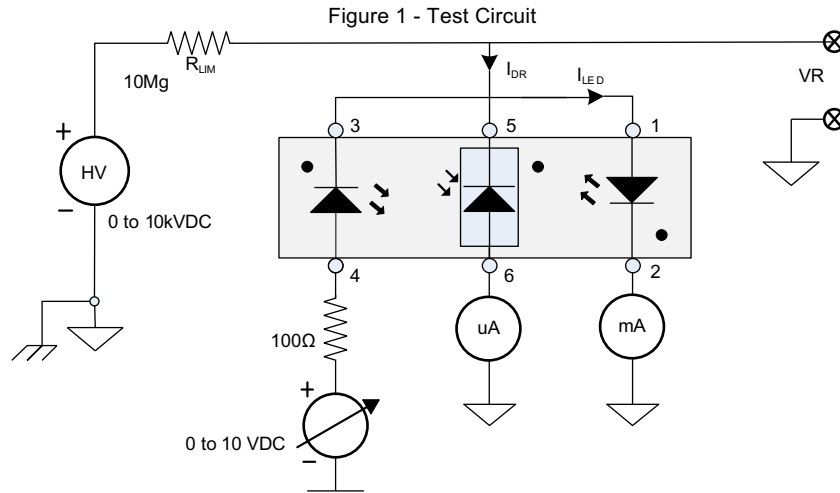


Figure 2 – Photo Detector Diode Current vs. LED Current

Detector Output Current vs. LED Input Current at 10kV

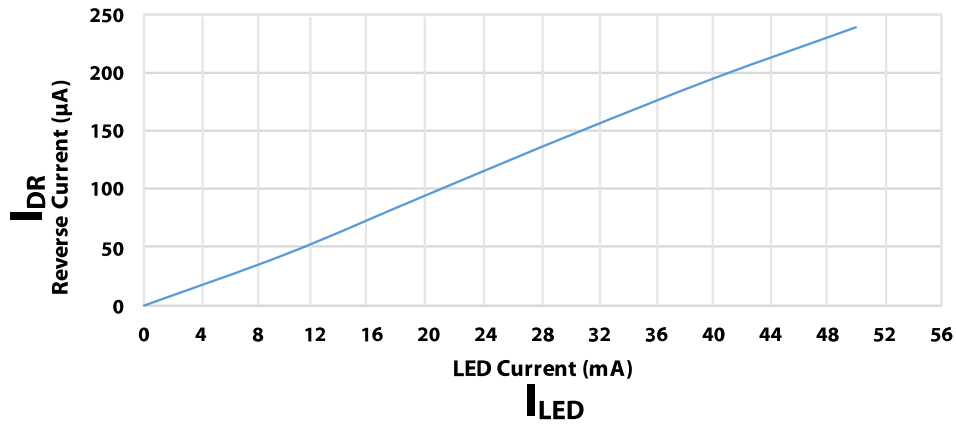
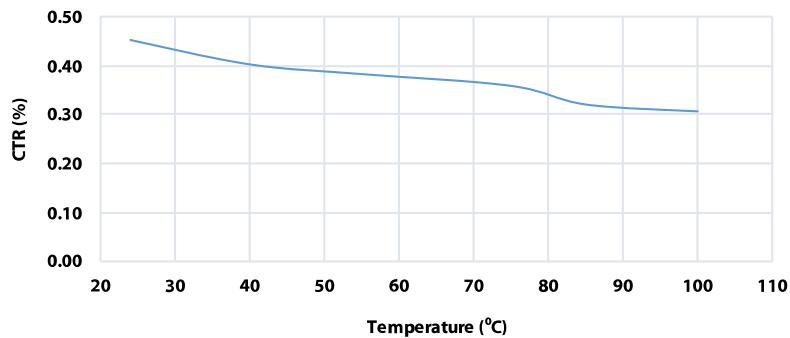


Figure 3 – Optocoupler Current Transfer Ratio vs. Ambient Temperature
(Represents use of OPC10M in Test Circuit)

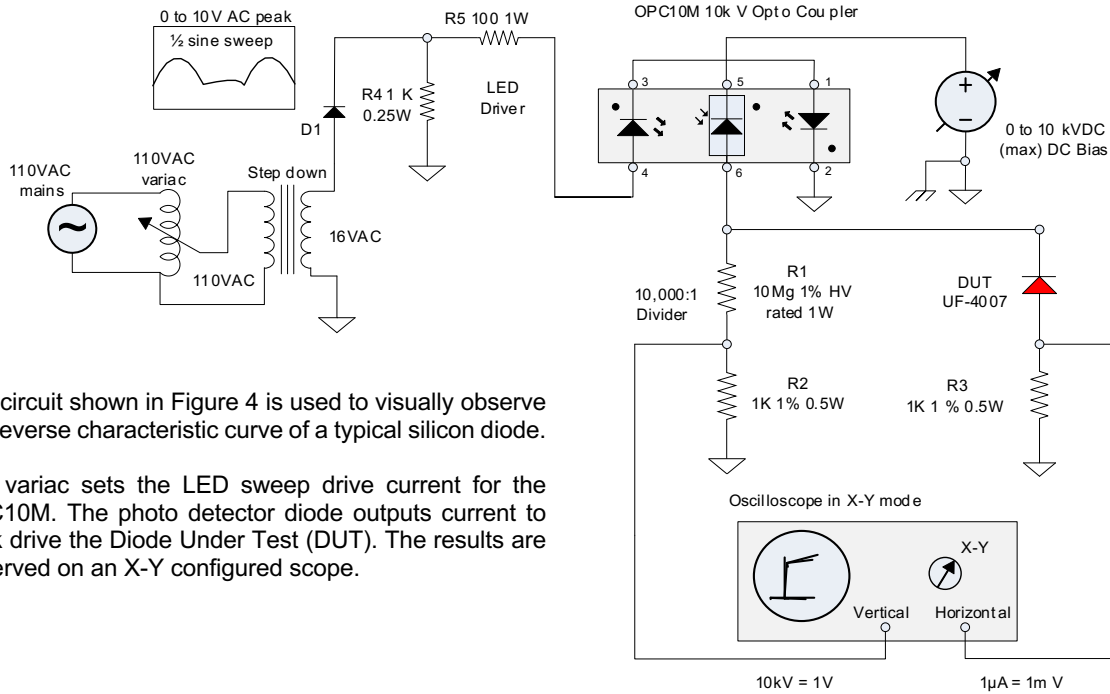
CTR (%) vs. Ambient Temperature





Sample Application Circuit

Figure 4 – Visual Diode Tester



The circuit shown in Figure 4 is used to visually observe the reverse characteristic curve of a typical silicon diode.

The variac sets the LED sweep drive current for the OPC10M. The photo detector diode outputs current to back drive the Diode Under Test (DUT). The results are observed on an X-Y configured scope.

Specification Definitions

| Specifications | Conditions |
|----------------------------------|--|
| V_{RRM} | Maximum Repetitive Reverse Voltage - |
| I_{FAVM} | Maximum Average Forward Current At T _A = 55°C |
| V_F | Maximum Forward Voltage Drop At I _F = 100mA |
| I_R² | Maximum Leakage Current At V _{DR} = V _{RRM} , I _{LED} = 0mA |
| I_{FSM} | Maximum Surge Current At 60Hz, Single Half Sine |
| C_J | Typical Junction Capacitance At V _R = 0VDC, f = 1MHz |
| CTR | Current Transfer Ratio I _{LED} = 50mA for 1 sec |
| t_{ON} | Turn-on Time - |
| t_{OFF} | Turn-off Time - |
| Insulation Voltage | - LED Drivers to Photo Detector Diode |
| I_{LED} | Forward DC Current - |
| V_{FLED} | Forward Voltage Drop At I _{LED} = 50mA |
| V_{RLED} | Reverse Voltage - |

²V_{DR} = Detector diode voltage in reverse.

Note: Specifications subject to change without notice. Photo is representation only.

